

Amendments to the Specification:

Please replace the paragraph beginning at page 2, line 15 as with the following amended paragraph:

U. S. Patent No. ~~5,339,151~~ 5,339,181 discloses a structure including a black matrix. In this technique, as shown in Fig. 2C of this patent, a black matrix extending from gate lines is so formed as to overlap with the edges of pixel electrodes. This structure is adapted to form auxiliary capacitors in overlapping portions of the black matrix and the pixel electrodes.